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	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.		
AFFEICATION NO.			98P7476US	9416		
09/052,688	03/31/1998	LAWRENCE A. CLEVENGER	70. 7. 7. 7. 7. 7. 7. 7. 7. 7. 7. 7. 7. 7.			
-	7590 03/28/2002					
SIEMENS CORPORATION INTELLECTUAL PROPERTY DEPARTMENT 186 WOOD AVENUE SOUTH			EXAMINER			
			PERALTA, GINETTE			
ISELIN, NJ (ART UNIT	PAPER NUMBER			
		2814				

DATE MAILED: 03/28/2002

Please find below and/or attached an Office communication concerning this application or proceeding.

<u></u>		Application I	No.		Applicant(s)			
Office Action Summary		09/052,688			CLEVENGER ET AL.			
		Examiner			Art Unit			
		Ginette Pera			2814			
The MAILING DATE of this communication appears on the cover sheet with the correspondence address								
Period for Reply								
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). - Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b). Status								
1) 🖾	Responsive to communication(s) filed on 12 I	February 2002	<u>2</u> .					
2a) □		nis action is no		l.				
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.								
Dispositi	on of Claims							
	4) Claim(s) 1-27 is/are pending in the application.							
	4a) Of the above claim(s) <u>6 and 16-27</u> is/are withdrawn from consideration.							
•	Claim(s) is/are allowed.							
•	6)⊠ Claim(s) <u>1-5 and 7-15</u> is/are rejected.							
-	Claim(s) is/are objected to.							
	Claim(s) are subject to restriction and/o	or election req	uirem	ent.				
• •	on Papers	ar						
	The specification is objected to by the Examine The drawing(s) filed on is/are: a)□ acce		biected	to by the Exa	miner.			
10)	Applicant may not request that any objection to the	ne drawing(s) be	e held	in abeyance. S	ee 37 CFR 1.85(a) .		
111	The proposed drawing correction filed on	is: a)☐ app	roved	b) disappro	ved by the Exam	iner.		
11)☐ The proposed drawing correction filed on is: a)☐ approved b)☐ disapproved by the Examiner. If approved, corrected drawings are required in reply to this Office action.								
12) The oath or declaration is objected to by the Examiner.								
Priority under 35 U.S.C. §§ 119 and 120								
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).								
a) ☐ All b) ☐ Some * c) ☐ None of:								
'	1. Certified copies of the priority documents have been received.							
	2. Certified copies of the priority documents have been received in Application No							
	3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).							
* See the attached detailed Office action for a list of the certified copies not received.								
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).								
a) The translation of the foreign language provisional application has been received. 15) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.								
Attachment(s)								
2) Noti	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO-948) rmation Disclosure Statement(s) (PTO-1449) Paper No(s)		5) 🔲 1	nterview Summar Notice of Informal Other:	y (PTO-413) Paper Patent Application (No(s) PTO-152)		

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DETAILED ACTION

Continued Examination Under 37 CFR 1.114

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 2/28/02 has been entered.

Claim Objections

2. Claim 1 is objected to because of the following informalities:

In line 12 of claim 1 it is recited "comprising a bottom surface and second and second sidewalls", it should be changed to "bottom surface and first and second sidewalls". Appropriate correction is required.

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

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4. Claims 1 are rejected under 35 U.S.C. 103(a) as being unpatentable over Teong (U. S. Pat. 5,693,563) in view of Hegde et al. (U. S. Pat. 6,136,682).

Teong teaches in Fig. 7 an integrated circuit comprising a dielectric layer formed over a substrate, a first damascene structure in the dielectric layer, the first damascene structure comprising a bottom surface and first and second sidewalls, a first conductor (18) located in the damascene structure, the conductor comprising a conductive material, a first liner layer (7) lining the bottom surface and sidewalls of the first damascene structure and encapsulating (11) the first conductor (18) by contacting a top surface of the first conductor, the liner layer comprising titanium nitride, a second damascene structure in the dielectric layer, the second damascene structure comprising a bottom surface and second sidewalls and disposed above the first damascene structure, a second conductor (28) located in the damascene structure, the conductor comprising a conductive material, a second liner layer (17) lining the bottom surface and sidewalls of the second damascene structure, and wherein the second liner layer is in contact with the first liner layer, wherein the material of the liner is titanium nitride, wherein the liner layer has a thickness between about 500 and 2000 Å, the structure further comprising a subliner (4,14) of titanium with a thickness between about 500 and 1500 Å, wherein the conductive material comprises copper, wherein the cavity that is filled with the conductor has a depth of between 2000 and 6000Å.

With respect to claim 9, the limitation of " N_2/H_2 plasma treated titanium nitride" is directed to a process for forming an amorphous titanium nitride layer. "Product by

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process" limitations in claims drawn to structure are directed to the product, and not the process by which the product was obtained.

With respect to claims 8 and 15, since applicants failed to show a critical nature of the claimed thickness pertaining unexpected results, further noting that it is well known and desirable in the art that to some extent scaling for higher density requires thinner device layers, it would have been obvious to one of ordinary skill in the art to vary the thickness of the titanium nitride layer and the aluminum layer.

Teong teaches all the limitations in the claims with the exception of disclosing a liner layer of an amorphous character that would impart a random grain orientation to the conductive material.

Hegde et al. teaches an integrated circuit comprising a dielectric layer formed over a substrate, a first damascene structure in the dielectric layer, the first damascene structure comprising a bottom surface and first and second sidewalls, a first conductor located in the damascene structure, a first liner layer lining the bottom surface and sidewalls of the first damascene structure, the liner layer being amorphous and thus imparting a random grain orientation in the conductive material of the first conductor to improve electromigration lifetime of the first conductor (col. 3, Il. 1-24), wherein the liner layer comprises tantalum nitride and titanium nitride, and the thickness of the liner layer is between about 0 to 400Å, and the structure comprising a subliner.

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Thus, it would have been obvious to one of ordinary skill in the art to use an amorphous titanium nitride layer in the invention of Teong et al. for the disclosed intended purpose of Hegde et al. of obtaining an improved copper barrier layer.

Furthermore, it would have been within the scope of one of ordinary skill in the art to form the liner layer of the second conductor to encapsulate the conductor as

Teong et al. teaches the feature in the first conductor and the repetition of a previously taught structure is not a patentable feature as it would not yield any unexpected results.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Ginette Peralta whose telephone number is (703)305-7722. The examiner can normally be reached on Monday to Friday 8:00 AM- 5:30 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Olik Chaudhuri can be reached on (703)306-2794. The fax phone numbers for the organization where this application or proceeding is assigned are (703)308-7722 for regular communications and (703)308-7724 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703)308-0956.

GP

March 18, 2002

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Olik Chaudhuri Supervisory Parant Fhaminer Technology Center 2006